## NSN 5961-01-305-9316

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laternal Confirmations
Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
5.00 milliamperes base current, dc blank
Power Rating Per Characteristic:
300.0 milliwatts small-signal input power, common-collector absolute
Transfer Ratio:
250.0 static forward current transfer ratio, common-emitter and 500.0 static forward current transfer ratio, common-emitter
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0